

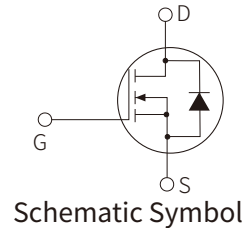
FEATURES

- | Surface-mounted package
- | Advanced trench cell design



APPLICATION

- | LCD TV appliances
- | LCDM appliances
- | High power inverter system



APPROVALS

RoHS	Compliance with 2011/65/EU
HF	Compliance with IEC61249-2-21:2003

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Drain-Source Voltage $T_c=25^\circ\text{C}$	V_{DS}	100	V
Drain Current (Pulsed) $T_c=25^\circ\text{C}$ $V_{GS}=10\text{V}$	I_{DM}^{***}	1168	A
Drain Current (DC) $T_c=25^\circ\text{C}$ $V_{GS}=10\text{V}$	I_D^{**}	292	A
Gate-Source Voltage $T_c=25^\circ\text{C}$	V_{GS}	± 20	V
Drain power dissipation $T_c=25^\circ\text{C}$	P_{tot}^*	312.5	W
Junction Temperature	T_J	175	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55 to 175	$^\circ\text{C}$
Single Pulsed Avalanche Energy $V_{DD}=50\text{V}$, $L=1\text{mH}$	E_{AS}^*	1225	mJ
Thermal Resistance – Junction to Ambient	$R_{\theta JA}^*$	45	$^\circ\text{C}/\text{W}$
Thermal Resistance- Junction to Case	$R_{\theta JC}^*$	0.3	$^\circ\text{C}/\text{W}$
Continuous-Source Current $T_c=25^\circ\text{C}$	I_S	292	A

Notes:

- * Surface Mounted on 1 in² pad area, $t \leq 10$ sec
- ** Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$
- *** Limited by bonding wire

ELECTRICAL CHARACTERISTICS (T_A=25°C)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _{DS} =250μA	100			V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _{DS} =250μA	2		4	V
Drain Leakage Current	I _{DSS}	V _{DS} =80V, V _{GS} =0V			1	μA
Gate Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V			±100	nA
On-State Resistance	R _{DS(on)} ^a	V _{GS} =10V, I _{DS} =50A		1.6	1.8	mΩ
Diode Characteristics						
Diode Forward Voltage	V _{SD} ^a	I _{SD} =50A, V _{GS} =0V			1.3	V
Reverse Recovery Time	t _{rr}	I _{DS} =50A dI _{SD} /dt=100A/μs		66		nS
Reverse Recovery Charge	Q _{rr}			200		nC
Dynamic Characteristics^b						
Input capacitance	C _{iss}	V _{GS} =0V, V _{DS} =50V, Frequency = 1 MHz		11132		pF
Output capacitance	C _{oss}			2780		pF
Reverse transfer capacitance	C _{rss}			532		pF
Turn-on Delay Time	t _{d(on)}	V _{DS} =50V, V _{GEN} =10V R _G =3.9Ω, R _L =1Ω I _{DS} =50A		59		nS
Turn-on Rise Time	t _r			66		nS
Turn-Off Delay Time	t _{d(off)}			185		nS
Turn-Off Fall Time	t _f			95		nS
Gate Charge Characteristics^b						
Total Gate Charge	Q _g	V _{DS} =50V, V _{GS} =10V, I _{DS} =50A		168		nC
Gate-Source Charge	Q _{gs}			59		nC
Gate-Drain Charge	Q _{gd}			35		nC

Notes:

a : Pulse test ; pulse width ≤ 300us, duty cycle ≤ 2 %

b : Guaranteed by design, not subject to production testing

PARAMETER CHARACTERISTIC CURVE

Figure1: Power Capability

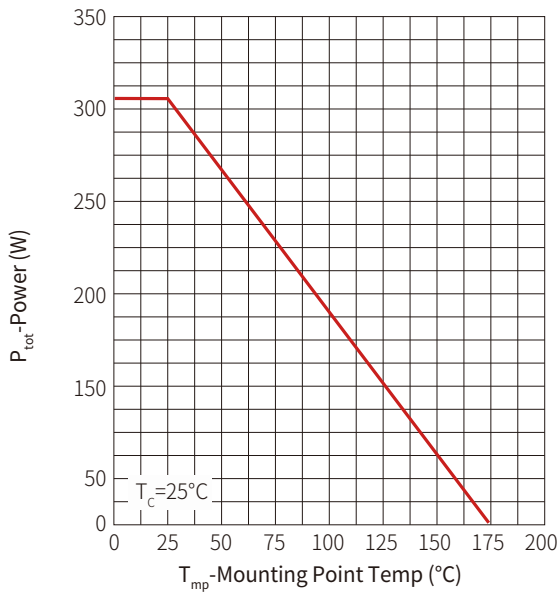


Figure2: Current Capability

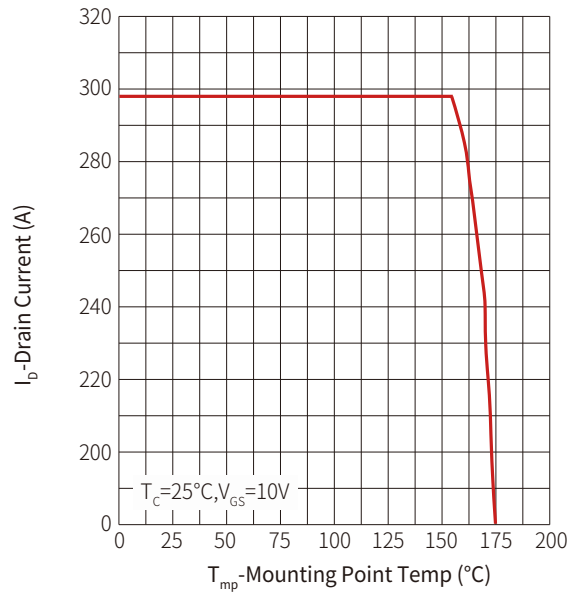


Figure3: Safe operating Area

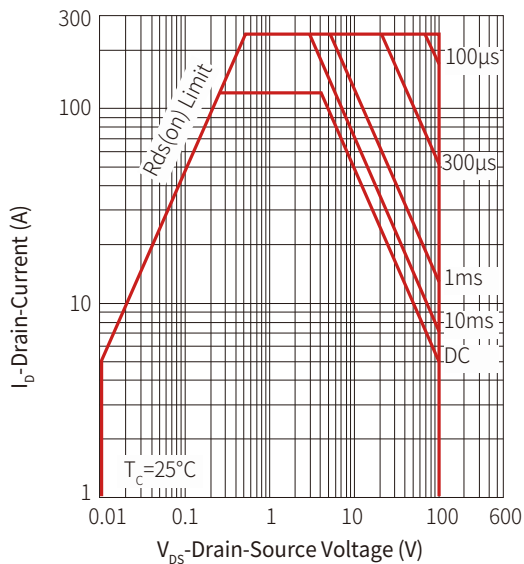


Figure 4: Transient Thermal Impedance

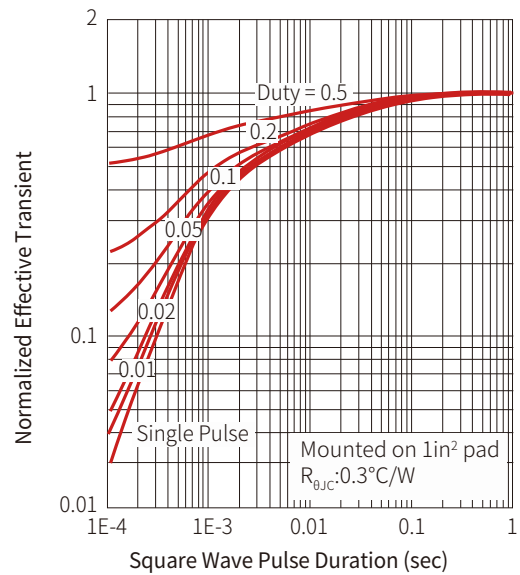


Figure 5: Output Characteristics

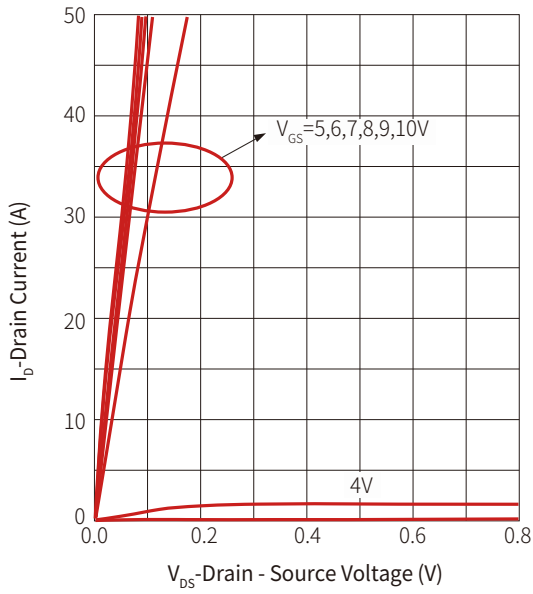


Figure 6: On Resistance

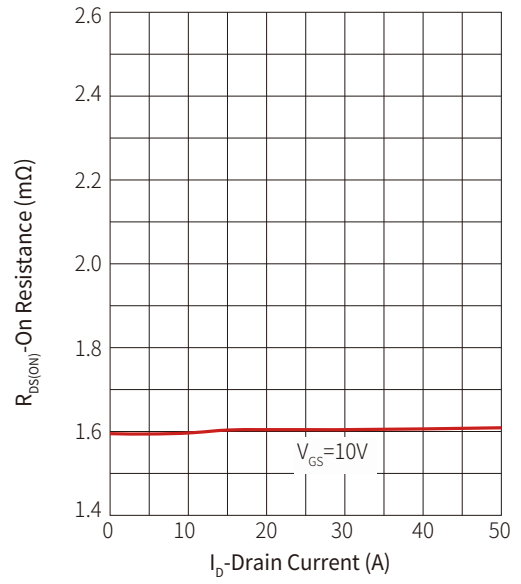


Figure 7: Transfer Characteristics

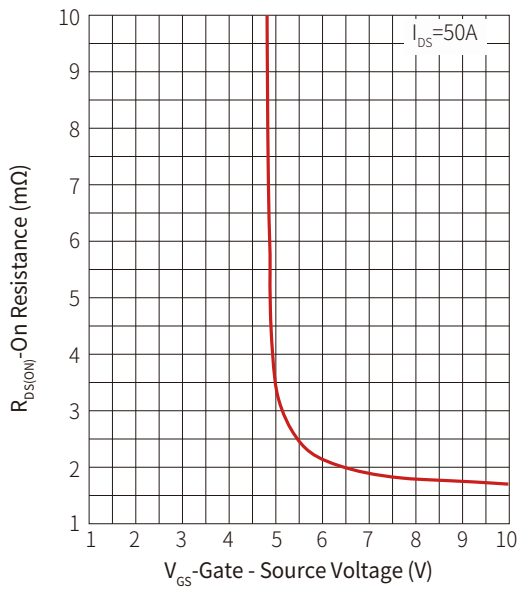


Figure 8: Normalized Threshold Voltage

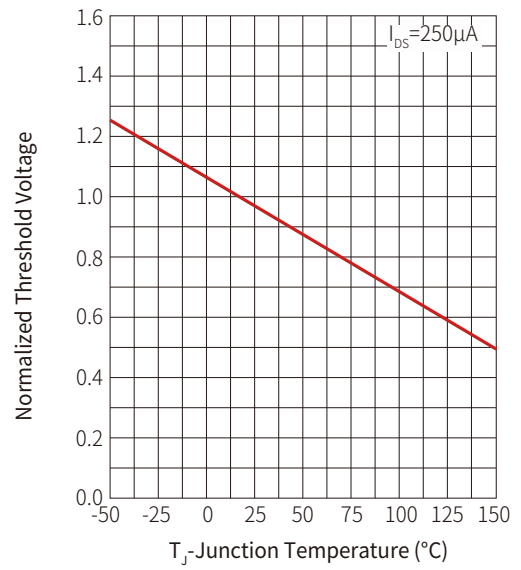


Figure 9: Normalized On Resistance

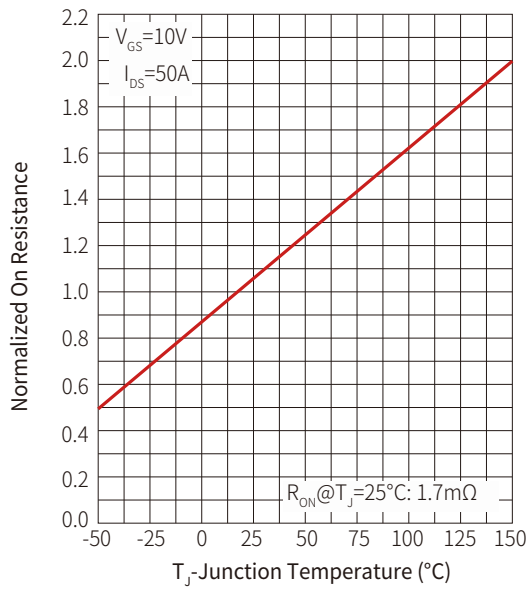


Figure 10: Diode Forward Current

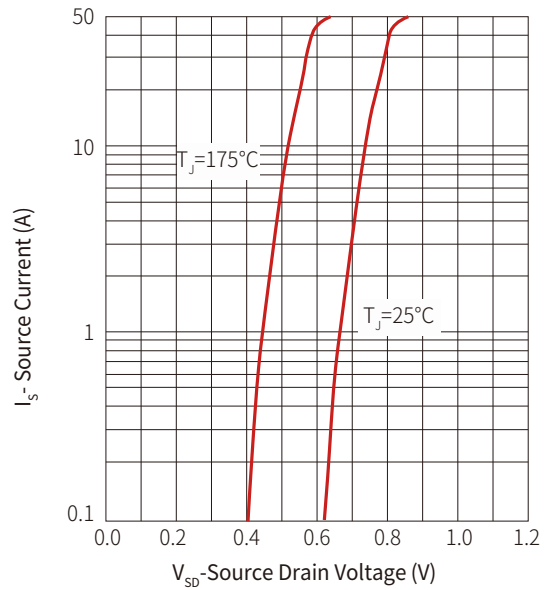


Figure 11: Capacitance

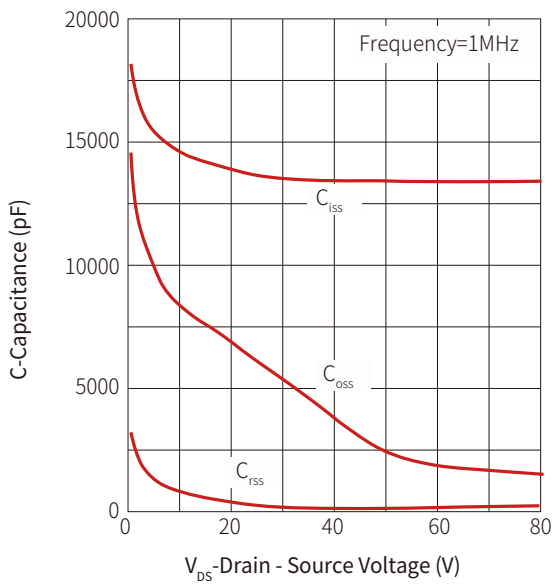
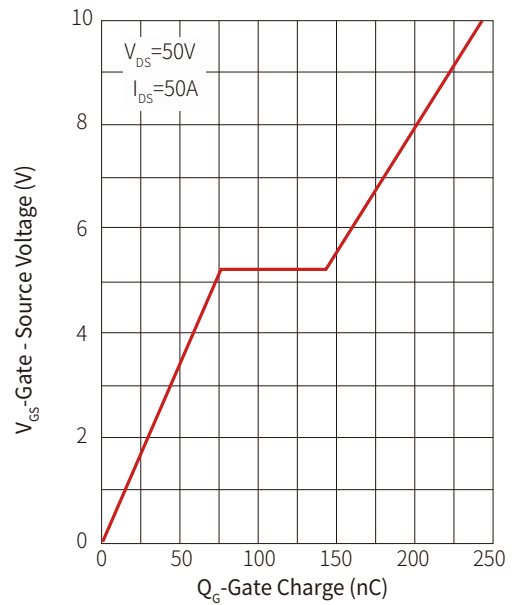



Figure 12: Gate Charge



ORDERING INFORMATION

Part Number	Component Package	Marking	QTY/Reel	QTY/Box
SNM018N10T	TOLL-8L	 018N10T XXXX	2000PCS	14000PCS

Headquarters

No.3387 Shendu Road
Pujiang I&E Park
Minhang Shanghai China
201000

Hotline

400-021-5756

Web

<https://www.semiware.com>

Sales Center

Tel: 86-21-3463-7458
Email: sales18@semiware.com

Customer Service

Tel: 86-21-5484-1001
Email: sales17@semiware.com

Technical Support

Tel: 86-21-3463-7654
Email: fae01@semiware.com

Complaint & Suggestions

Tel: 86-21-3463-7172
Ext: 8868
Email: cs03@semiware.com

By QR Code

Website



Wechat

To find your local partner within Semiware' s global website: www.semiware.com

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